
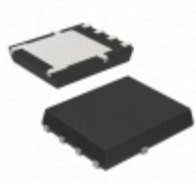
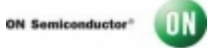
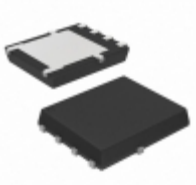
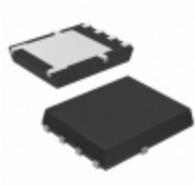
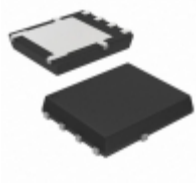
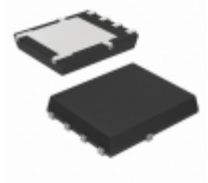
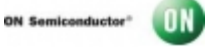
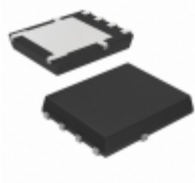
	<h2 style="color: #E67E22;">NVMFS4C05NWFT1G</h2>
	<p>Hersteller-Teilenummer: NVMFS4C05NWFT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 116A SO8FL</p> <hr/> <p>Datenblätter:  NVMFS4C05NWFT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS4C05NWFT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 116A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2.2V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	3.4 mOhm @ 30A, 10V
Verlustleistung (max)	3.61W (Ta), 79W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1972pF @ 15V
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	24.7A (Ta), 116A (Tc)

NVMFS4C05NWFT1G Electronic Components ist ein 100% neues Original von YIC Distributor, NVMFS4C05NWFT1G-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, NVMFS4C05NWFT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.
RFQ NVMFS4C05NWFT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMFS4C310NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS4C310NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS4C302NT1G AMI Semiconductor / ON Semiconductor NFET SO8FL 30V 1.15MO</p>	 <p>NVMFS4C03NWFT1G ON Semiconductor MOSFET N-CH 30V 31.4A SO8FL</p>
 <p>NVMFS4C03NWFT3G ON Semiconductor MOSFET N-CH 30V 31.4A SO8FL</p>	 <p>NVMFS4C05NT1G ON Semiconductor MOSFET N-CH 30V 116A SO8FL</p>	 <p>NVMFS4C05N ON NVMFS4C05N ON</p>	 <p>NVMFS4C05NWFT3G ON Semiconductor MOSFET N-CH 30V 116A SO8FL</p>

Verwandtes Hot-Keyword

Mehr

NVMFS4C05NWFT1G AMI Semiconductor / ON Semiconductor	NVMFS4C05NWFT1G Datenblatt	NVMFS4C05NWFT1G-Datenblätter	NVMFS4C05NWFT1G PDF	AMI Semiconductor / ON Semiconductor NVMFS4C05NWFT1G
NVMFS4C05NWFT1G Electronic	NVMFS4C05NWFT1G-Komponenten	NVMFS4C05NWFT1G-Verteiler	NVMFS4C05NWFT1G-Bild	NVMFS4C05NWFT1G-Teil
NVMFS4C05NWFT1G Preis	NVMFS4C05NWFT1G Hersteller	NVMFS4C05NWFT1G Bild	NVMFS4C05NWFT1G Aktie	NVMFS4C05NWFT1G Inventar
NVMFS4C05NWFT1G Neu	NVMFS4C05NWFT1G Original	NVMFS4C05NWFT1G garantiert	NVMFS4C05NWFT1G RFQ	NVMFS4C05NWFT1G Online bestellen

Contact us:Info@Y-IC.com

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